TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC390AP,TC74HC390AF,TC74HC390AFN

Dual Decade Counter

The TC74HC390A is a high speed CMOS DUAL DECADE COUNTER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

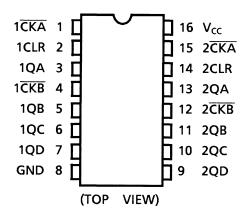
It consists of two independent 4-bit counters, each composed of a divide-by-two and a divide-by-five counter. The divide-by-two counter is incremented on the negative going transition of clock A $(\overline{CKA}\,)$. The divided-by-five counter is incremented on the negative going transition of clock B $(\overline{CKB}\,)$. The counter can be cascaded to form decade, bi-quinary, or various combinations up to a divide-by-100 counter. When the CLR input is set high, the Q outputs are set to low independent of the clock inputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

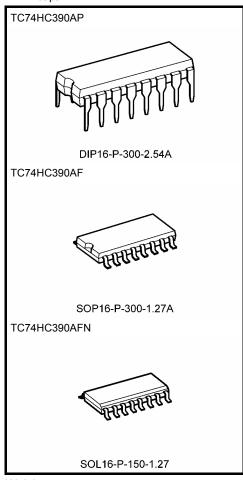
Features

- High speed: $f_{max} = 84 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 4 \text{ mA (min)}$
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2~6 V
- Pin and function compatible with 74LS390

Pin Assignment



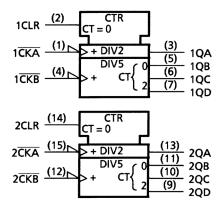
Note: xxxFN (JEDEC SOP) is not available in Japan.



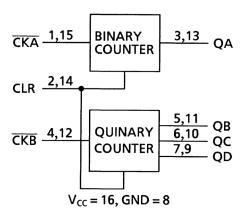
Weight

DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.) SOL16-P-150-1.27 : 0.13 g (typ.)

IEC Logic Symbol



Block Diagram



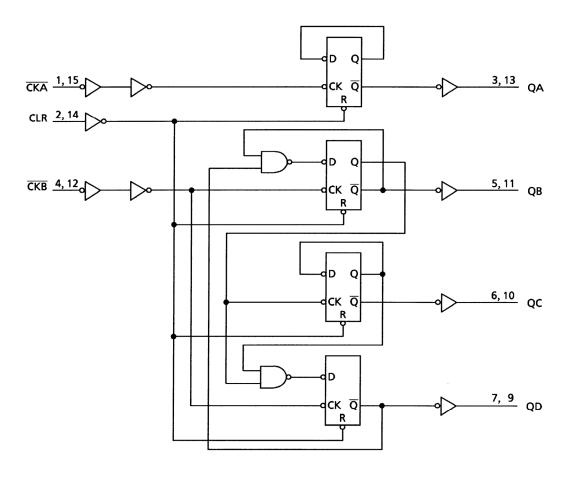
Truth Table

	Inputs		Outputs						
CKA	CKB	CLR	QA	QC	QD				
Х	Х	Н	L	L	L	L			
\neg	Х	L	Binary Count Up Quinary Count Up						
Х	\neg	L							

X: Don't care

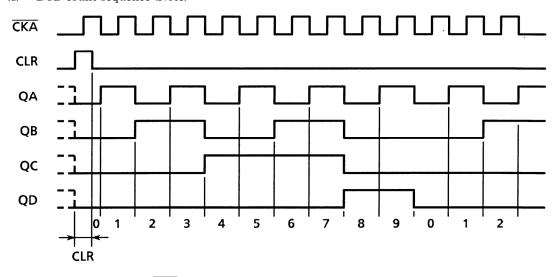
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System Diagram (1/2 package)



Timing Chart

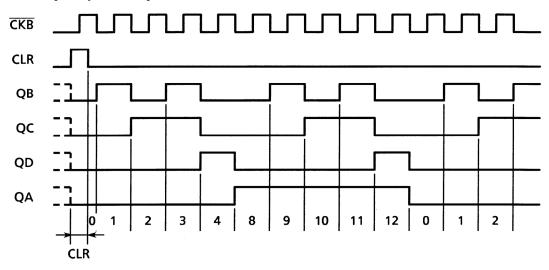
(1) BCD count sequence (Note)



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Note: QA connected to CKB

(2) BI-quinary count sequence (Note)



Note: QD connected to CKA

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	−65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = $-40 \text{ to } 65^{\circ}\text{C}$. From Ta = $65 \text{ to } 85^{\circ}\text{C}$ a derating factor of $-10 \text{ mW}/^{\circ}\text{C}$ shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2~6	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
		0~1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0~500 (V _{CC} = 4.5 V)	ns
		0~400 (V _{CC} = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			-	Га = 25°C		Ta = -40~85°C		Unit
Characteristics	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
				2.0	1.50	_	_	1.50	_	
High-level input voltage	V _{IH}		_	4.5	3.15	_	_	3.15	_	V
ŭ				6.0	4.20	_	_	4.20	_	
				2.0	_	_	0.50	_	0.50	
Low-level input voltage	V _{IL}	_		4.5	_	_	1.35	_	1.35	V
				6.0	_	_	1.80	_	1.80	
	V _{ОН}	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_	
			$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	
High-level output voltage				6.0	5.9	6.0	_	5.9	_	V
			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
	V _{OL}	V _{IN} = V _{IH} or V _{IL}		2.0	_	0.0	0.1	_	0.1	
			$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage				6.0	_	0.0	0.1	_	0.1	V
			I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33	
			$I_{OL} = 5.2 \text{ mA}$	6.0	_	0.18	0.26	_	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0		_	±0.1	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or	V _{IN} = V _{CC} or GND		_		4.0	_	40.0	μА

Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 ~85°C	Unit	
			V _{CC} (V)	Тур.	Limit	Limit		
Minimum pulse width	5		2.0	_	75	95		
(CK)	tw (H)	_	4.5	_	15	19	ns	
(OK)	t _{W (L)}		6.0	_	13	16		
Minimum pulse width			2.0	_	75	95		
(CLR)	t _{W (H)}	_	4.5	_	15	19	ns	
(OLN)			6.0	_	13	16		
	t _{rem}		2.0	_	25	30	ns	
Minimum removal time		_	4.5	_	5	6		
			6.0	_	5	5		
Clock frequency			2.0	_	6	5		
(CKA)	f	_	4.5	_	32	26	MHz	
(CRA)			6.0	_	38	31		
Clock fraguency			2.0	_	6	5		
Clock frequency	f	_	4.5	_	31	25	MHz	
(CKB)			6.0	_	36	29		

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AC Characteristics (C_L = 15 pF, V_{CC} = 5 V, Ta = 25°C input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t _{TLH}	_	_	4	8	ns
	t _{THL}					
Propagation delay time	t _{pLH}			10	20	ns
(CKA -QA)	t _{pHL}					113
Propagation delay time	t _{pLH}	QA connected to CKB		29	51	ns
(CKA -QC)	t _{pHL}	QA COMMECTED TO CIVID				113
Propagation delay time	t _{pLH}			12	22	ns
(CKB -QB, QD)	t _{pHL}	_		12	22	115
Propagation delay time	t _{pLH}			17	32	ns
(CKB -QC)	t _{pHL}			17	32	113
Propagation delay time	+			12	26	ns
(CLR-Qn)	t _{pHL}	_		12	20	115
Maximum clock frequency			25	0.4		N41.1-
(CKA)	f _{max}	_	35	84	_	MHz
Maximum clock frequency	f		33	65		MHz
(CKB)	f _{max}	_	33	05		IVI⊓∠



AC Characteristics ($C_L = 50$ pF, input: $t_r = t_f = 6$ ns)

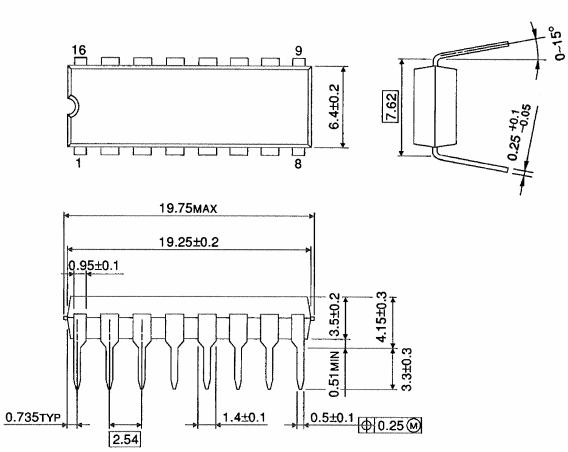
Characteristics	Symbol	Test Condition			Ta = 25°0	2	Ta = -4	Unit	
Ondi dotoriotico Oyiiiboi		VC		Min	Тур.	Max	Min		Max
	t _{TLH}		2.0	_	30	75	_	95	
Output transition time		_	4.5	_	8	15	_	19	ns
	t _{THL}		6.0	_	7	13	_	16	
Propagation delay	t _{pLH}		2.0	_	39	120	_	150	
time	t _{pHL}	_	4.5	_	13	24	_	30	ns
(CKA -QA)	φпь		6.0	_	11	20	_	26	
Propagation delay	t _{pLH}		2.0	_	102	290	_	365	
time ——	t _{pHL}	QA connected to CKB	4.5	_	34	58	_	73	ns
(CKA -QC)	φпь		6.0	_	29	49	_	62	
Propagation delay	t_{pLH}		2.0	_	45	130	_	165	
time ——	t _{pHL}	_	4.5	_	15	26	_	33	ns
(CKB -QB, QD)	φн∟		6.0	_	13	22	_	28	
Propagation delay	t _{pLH}	_	2.0	_	63	185	_	230	
time	t _{pHL}		4.5	_	21	37	_	46	ns
(CKB -QC)	φпь		6.0	_	18	31	_	39	
Propagation delay			2.0	_	45	150	_	190	
time	t_pHL	_	4.5	_	15	30	_	38	ns
(CLR-Qn)			6.0	_	13	26	_	32	
Maximum clock			2.0	6	20	_	5	_	
frequency	f_{max}	_	4.5	32	77	_	26	_	MHz
(CKA)			6.0	38	90	_	31		
Maximum clock			2.0	6	15	_	5	_	
frequency	f_{max}	_	4.5	32	60	_	25	_	MHz
(CKB)			6.0	36	70		29		
Input capacitance	C _{IN}				5	10	_	10	pF
Power dissipation	C _{PD}				44			_	pF
capacitance	(Note)								۲,

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ (per counter)

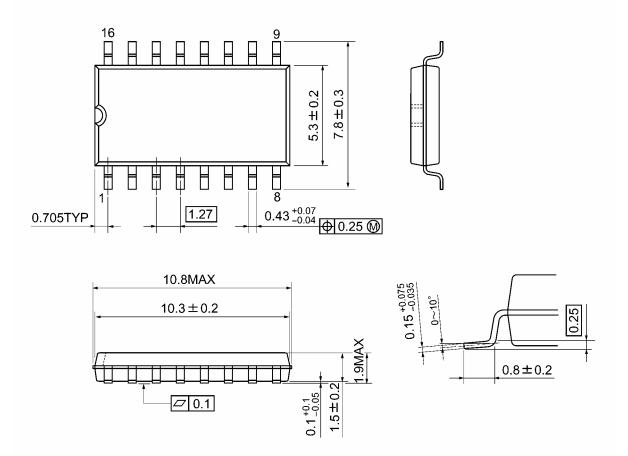
Package Dimensions



Weight: 1.00 g (typ.)

Package Dimensions

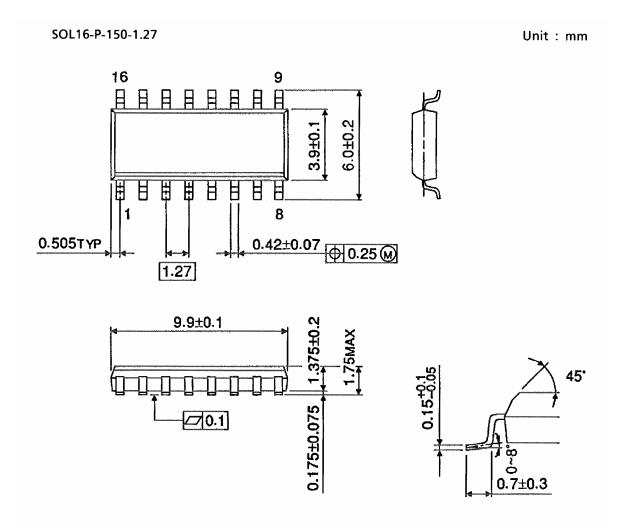
SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)



Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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20070701-EN GENERAL

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